

# **Description**

The SVD2955 uses advanced trench

technology to provide excellent R<sub>DS(ON)</sub>, low gate

charge and operation with gate voltages as low

as 4.5V. This device is suitable for use as a

Battery protection or in other Switching application.



### TO-252-2L

## **General Features**

 $V_{DS} = -60V I_{D} = -10 A$ 

 $R_{DS(ON)}$  < 140m $\Omega$  @  $V_{GS}$ =10V

# G S S

# **Application**

Brushless motor

Load switch

Uninterruptible power supply

P-Channel MOSFET

## **Package Marking and Ordering Information**

| Product ID | Pack      | Brand      | Qty(PCS) |
|------------|-----------|------------|----------|
| SVD2955    | TO-252-2L | HXY MOSFET | 2500     |

#### Absolute Maximum Ratings (T<sub>c</sub>=25°Cunless otherwise noted)

| Symbol                                | Parameter   | Rating  | Units |  |  |
|---------------------------------------|---|---|-------|--|--|
| V <sub>DS</sub>                       | Drain-Source Voltage  | -60   | V     |  |  |
| Vgs                                   | Gate-Source Voltage   | ±20   | V     |  |  |
| I <sub>D</sub> @T <sub>C</sub> =25°C  | Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup> | Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup> -10 |       |  |  |
| I <sub>D</sub> @T <sub>C</sub> =100°C | Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup> | -8.3  | Α     |  |  |
| Ірм                                   | Pulsed Drain Current <sup>2</sup> -26                         |   | А     |  |  |
| EAS                                   | Single Pulse Avalanche Energy <sup>3</sup>                    | 29.8  | mJ    |  |  |
| las                                   | Avalanche Current   | -24.4   | Α     |  |  |
| $P_D@T_C=25^{\circ}C$                 | Total Power Dissipation <sup>4</sup>                          | 31.3  | W     |  |  |
| Тѕтс                                  | Storage Temperature Range                                     | -55 to 150  | °C    |  |  |
| TJ                                    | Operating Junction Temperature Range                          | -55 to 150  | °C    |  |  |
| Reja                                  | Thermal Resistance Junction-Ambient <sup>1</sup>              | 62  | °C/W  |  |  |
| Rejc                                  | Thermal Resistance Junction-Case <sup>1</sup>                 | 4.0   | °C/W  |  |  |



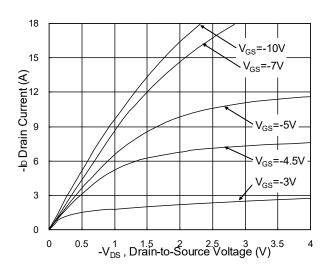
# Electrical Characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)

| Symbol                 | Parameter                                      | Conditions   | Min.  | Тур.   | Max. | Unit     |
|------------------------|--|--|---|--------|------|----------|
| BV <sub>DSS</sub>      | Drain-Source Breakdown Voltage                 | V <sub>GS</sub> =0V , I <sub>D</sub> =-250uA                         | -60   |        | -    | <b>V</b> |
| △BV <sub>DSS</sub> /△T | BV <sub>DSS</sub> Temperature Coefficient      | Reference to 25°C , I <sub>D</sub> =-1mA                             |   | -0.049 |      | V/°C     |
| R <sub>DS(ON)</sub>    | Static Drain-Source On-Resistance <sup>2</sup> | V <sub>GS</sub> =-10V , I <sub>D</sub> =-8A                          |   | 125    | 140  | mΩ       |
|                        | Static Drain-Source On-Resistance              | V <sub>GS</sub> =-4.5V , I <sub>D</sub> =-6A                         |   | 168    | 210  |          |
| V <sub>GS(th)</sub>    | Gate Threshold Voltage                         | V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =-250uA            | -1.0  |        | -2.5 | V        |
| $\triangle V_{GS(th)}$ | V <sub>GS(th)</sub> Temperature Coefficient    | VGS-VDS , ID250UA  |   | 5.42   |      | mV/°C    |
|                        | Drain Source Leakage Current                   | V <sub>DS</sub> =-48V , V <sub>GS</sub> =0V , T <sub>J</sub> =25°C   |   |        | 1    | uA       |
| I <sub>DSS</sub>       | Drain-Source Leakage Current                   | V <sub>DS</sub> =-48V , V <sub>GS</sub> =0V , T <sub>J</sub> =150°C  | / <sub>GS</sub> =0V , T <sub>J</sub> =150°C |        | 5    | ] uA     |
| I <sub>GSS</sub>       | Gate-Source Leakage Current                    | V <sub>GS</sub> =±20V , V <sub>DS</sub> =0V                          |   |        | ±100 | nA       |
| gfs                    | Forward Transconductance                       | V <sub>DS</sub> =-5V , I <sub>D</sub> =-5A                           |   | 5.8    |      | S        |
| Qg                     | Total Gate Charge (-4.5V)                      |  |   | 5.85   |      | nC       |
| Q <sub>gs</sub>        | Gate-Source Charge                             | V <sub>DS</sub> =-20V , V <sub>GS</sub> =-4.5V , I <sub>D</sub> =-5A |   | 2.9    |      |          |
| Q <sub>gd</sub>        | Gate-Drain Charge                              |  |   | 1.8    |      |          |
| T <sub>d(on)</sub>     | Turn-On Delay Time                             |  |   | 10     |      |          |
| T <sub>r</sub>         | Rise Time                                      | $V_{DD}$ =-12V , $V_{GS}$ =-10V , $R_{G}$ =3.3 $\Omega$ ,            |   | 17     |      | ns       |
| T <sub>d(off)</sub>    | Turn-Off Delay Time                            | I <sub>D</sub> =-5A  |   | 22     |      |          |
| T <sub>f</sub>         | Fall Time                                      |  |   | 21     |      |          |
| C <sub>iss</sub>       | Input Capacitance                              |  |   | 715    |      |          |
| Coss                   | Output Capacitance                             | V <sub>DS</sub> =-15V , V <sub>GS</sub> =0V , F=1MHz                 |   | 51     |      | pF       |
| C <sub>rss</sub>       | Reverse Transfer Capacitance                   |  |   | 34     |      |          |
| Is                     | Continuous Source Current <sup>1,5</sup>       | V =V =0V Force Current   |   |        | -9.5 | Α        |
| I <sub>SM</sub>        | Pulsed Source Current <sup>2,5</sup>           | V <sub>G</sub> =V <sub>D</sub> =0V , Force Current                   |   |        | -24  | Α        |
| V <sub>SD</sub>        | Diode Forward Voltage <sup>2</sup>             | V <sub>GS</sub> =0V , I <sub>S</sub> =-1A , T <sub>J</sub> =25°C     |   |        | -1.2 | ٧        |
| t <sub>rr</sub>        | Reverse Recovery Time                          |  |   | 10.2   |      | nS       |
| Q <sub>rr</sub>        | Reverse Recovery Charge                        | IF=-8A,dI/dt=100A/μs,T <sub>J</sub> =25°C                            |   | 5.4    |      | nC       |

#### Note:

- 1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
- 2. The data tested by pulsed , pulse width  $\,\leq\,300\text{us}$  , duty cycle  $\,\leq\,2\%$
- 3. The EAS data shows Max. rating. The test condition is  $V_{DD}$ =-25V, $V_{GS}$ =-10V,L=0.1mH, $I_{AS}$ =-15A
- 4. The power dissipation is limited by 150°C junction temperature
- 5. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.

# **Typical Characteristics**



**Fig.1 Typical Output Characteristics** 

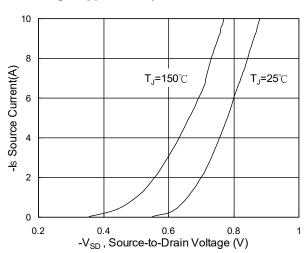


Fig.3 Forward Characteristics Of Reverse

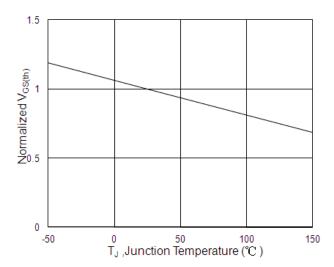


Fig.5 Normalized  $V_{\text{GS(th)}}$  vs.  $T_{\text{J}}$ 

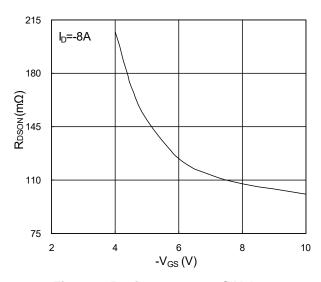


Fig.2 On-Resistance vs. G-S Voltage

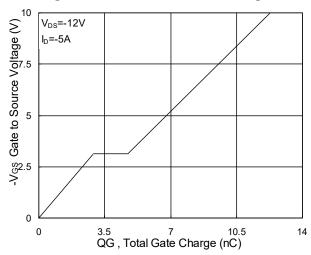


Fig.4 Gate-Charge Characteristics

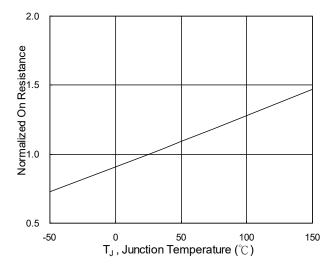
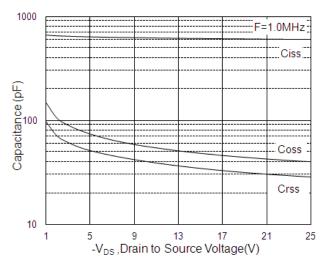


Fig.6 Normalized  $R_{DSON}$  vs.  $T_J$ 



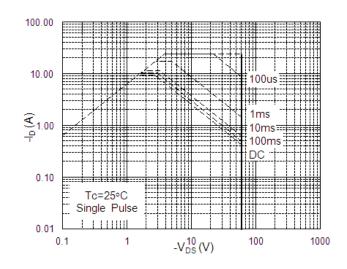


Fig.7 Capacitance

Fig.8 Safe Operating Area

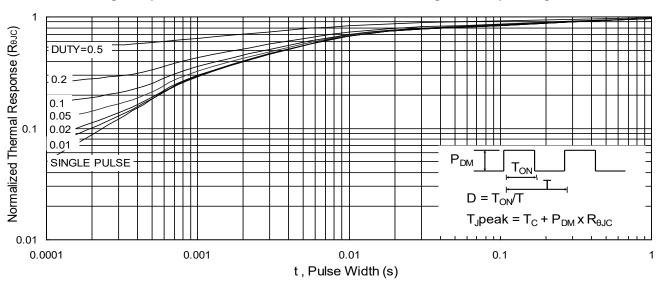
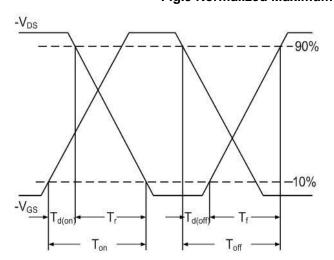


Fig.9 Normalized Maximum Transient Thermal Impedance



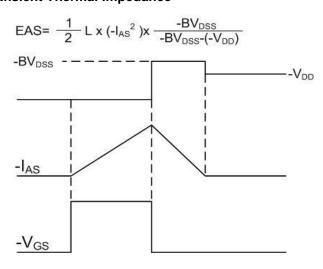
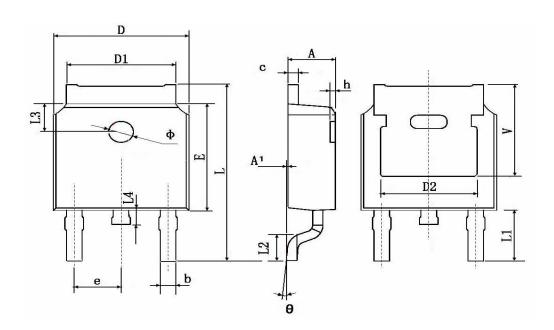


Fig.11 Unclamped Inductive Switching Waveform

# **TO-252-2L Package Information**



| Dimensions In Millimeters |   | Dimensions In Inches  |   |  |
|---------------------------|---|---|---|--|
| Min.                      | Max.  | Min.  | Max.  |  |
| 2.200                     | 2.400   | 0.087   | 0.094   |  |
| 0.000                     | 0.127   | 0.000   | 0.005   |  |
| 0.660                     | 0.860   | 0.026   | 0.034   |  |
| 0.460                     | 0.580   | 0.018   | 0.023   |  |
| 6.500                     | 6.700   | 0.256   | 0.264   |  |
| 5.100                     | 5.460   | 0.201   | 0.215   |  |
| 4.830 TYP.                |   | 0.190 TYP.  |   |  |
| 6.000                     | 6.200   | 0.236   | 0.244   |  |
| 2.186                     | 2.386   | 0.086   | 0.094   |  |
| 9.800                     | 10.400  | 0.386   | 0.409   |  |
| 2.900 TYP.                |   | 0.114 TYP.  |   |  |
| 1 400                     | 1 700   | 0.055   | 0.067   |  |
|                           |   | 0.063 TYP.  |   |  |
| 0.600                     | 1.000   | 0.024   | 0.039   |  |
| 1.100                     | 1.300   | 0.043   | 0.051   |  |
| 0°                        | 8°  | 0°  | 8°  |  |
| 0.000                     | 0.300   | 0.000   | 0.012   |  |
| 5.350 TYP.                |   | 0.211 TYP.  |   |  |
|                           | Min. 2.200 0.000 0.660 0.460 6.500 5.100 4.830 6.000 2.186 9.800 2.900 1.400 1.600 0.600 1.100 0° 0.000 | Min.         Max.           2.200         2.400           0.000         0.127           0.660         0.860           0.460         0.580           6.500         6.700           5.100         5.460           4.830 TYP.         6.200           2.186         2.386           9.800         10.400           2.900 TYP.         1.700           1.600 TYP.         0.600           1.100         1.300           0°         8°           0.000         0.300 | Min.         Max.         Min.           2.200         2.400         0.087           0.000         0.127         0.000           0.660         0.860         0.026           0.460         0.580         0.018           6.500         6.700         0.256           5.100         5.460         0.201           4.830 TYP.         0.190           6.000         6.200         0.236           2.186         2.386         0.086           9.800         10.400         0.386           2.900 TYP.         0.114           1.400         1.700         0.055           1.600 TYP.         0.063           0.600         1.000         0.024           1.100         1.300         0.043           0°         8°         0°           0.000         0.300         0.000 |  |



### **Attention**

- Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.
- HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.
- Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.

  HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc.

  When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by HXY MOS manufacturer:

Other Similar products are found below:

IRFD120 JANTX2N5237 BUK455-60A/B MIC4420CM-TR VN1206L NDP4060 SI4482DY IPS70R2K0CEAKMA1 SQD23N06-31L-GE3
TK16J60W,S1VQ(O 2SK2614(TE16L1,Q) DMN1017UCP3-7 DMN1053UCP4-7 SQJ469EP-T1-GE3 NTE2384 DMC2700UDMQ-7
DMN2080UCB4-7 DMN61D9UWQ-13 US6M2GTR DMN31D5UDJ-7 DMP22D4UFO-7B DMN1006UCA6-7 DMN16M9UCA6-7
STF5N65M6 IRF40H233XTMA1 STU5N65M6 DMN6022SSD-13 DMN13M9UCA6-7 DMTH10H4M6SPS-13 DMN2990UFB-7B
IPB80P04P405ATMA2 2N7002W-G MCAC30N06Y-TP MCQ7328-TP NTMC083NP10M5L NVMFS2D3P04M8LT1G BXP7N65D
BXP4N65F AOL1454G WMJ80N60C4 BXP2N20L BXP2N65D BXT1150N10J BXT1700P06M TSM60NB380CP ROG RQ7L055BGTCR
DMNH15H110SK3-13 SLF10N65ABV2 BSO203SP BSO211P